

**PRODUCT RELIABILITY REPORT
FOR**

DS3992, Rev A2

Dallas Semiconductor

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Prepared by:

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Conclusion:

The following qualification successfully meets the quality and reliability standards required of all Dallas Semiconductor products:

DS3992, Rev A2

In addition, Dallas Semiconductor's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at <http://www.maxim-ic.com/TechSupport/dsreliability.html>.

Device Description:

A description of this device can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l_datasheet3.cfm.

Reliability Derating:

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

$$AfT = \exp((Ea/k) * (1/Tu - 1/Ts)) = tu/ts$$

AfT = Acceleration factor due to Temperature
tu = Time at use temperature (e.g. 55°C)
ts = Time at stress temperature (e.g. 125°C)
k = Boltzmann's Constant (8.617 x 10⁻⁵ eV/°K)
Tu = Temperature at Use (°K)
Ts = Temperature at Stress (°K)
Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

$$AfV = \exp(B * (Vs - Vu))$$

AfV = Acceleration factor due to Voltage
Vs = Stress Voltage (e.g. 7.0 volts)
Vu = Maximum Operating Voltage (e.g. 5.5 volts)
B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

$$Fr = X / (ts * AfV * AfT * N * 2)$$

X = Chi-Sq statistical upper limit
N = Life test sample size

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

$$MTTF = 1/Fr$$

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

FAILURE RATE:	MTTF (YRS):	110810	FITS:	1.0
	DEVICE HOURS:	943032	FAILS:	0

Only data from Operating Life or similar stresses are used for this calculation.

The parameters used to calculate this failure rate are as follows:

Cf: 60% **Ea: 0.7** **B: 0** **Tu: 25 °C** **Vu: 3 Volts**

The reliability data follows. At the start of this data is the device information. The next section is the detailed reliability data for each stress. The reliability data section includes the latest data available and may contain some generic data. "*" after DATE CODE denotes specific product data and SEQ No. to identify specific line items in the report for comments when required.

Device Information:

Process: E35WN-3P3M,DPE2,NTC,DSD,PDES,DRES,Cap,ENPN,DPT,HTO,SgHalo
 Passivation: TEOS Ox-Nit 2-Mask Laser/Pass for E35WM; Full BEOL at X3; PT only in Dallas
 Die Size: 86 x 108
 Number of Transistors: 53363
 Interconnect: Aluminum / 0.5% Copper
 Gate Oxide Thickness: 120 Å

ELECTRICAL CHARACTERIZATION

DESCRIPTION	DATE CODE/SEQ	CONDITION	READPOINT	QTY	FAILS	FA#
ESD SENSITIVITY	0625 * 1	EOS/ESD S5.1 HBM 500 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0625 * 2	EOS/ESD S5.1 HBM 1000 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0625 * 3	EOS/ESD S5.1 HBM 2000 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0625 * 4	EOS/ESD S5.1 HBM 3000 VOLTS	1 PUL'S	3	0	
ESD SENSITIVITY	0625 * 5	EOS/ESD S5.1 HBM 4000 VOLTS	1 PUL'S	3	3	No FA
LATCH-UP	0625 * 6	JESD78, I-TEST 125C		6	0	
LATCH-UP	0625 * 7	JESD78, V-SUPPLY TEST 125C		6	0	
Total:					3	

OPERATING LIFE

DESCRIPTION	DATE CODE/SEQ	CONDITION	READPOINT	QTY	FAILS	FA#
HIGH TEMP OP LIFE	0538	125C, 5.5 VOLTS	1000 HRS	77	0	
HIGH TEMP OP LIFE	0541	125C, 5.5 VOLTS	1000 HRS	77	0	
HIGH TEMP OP LIFE	0602	125C, 5.5 V (PSA) & 0.0 V (PSB)	1000 HRS	77	0	
HIGH TEMP OP LIFE	0604	125C, 5.5 VOLTS	1000 HRS	77	0	

HIGH TEMP OP LIFE	0620		125C, 5.25 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0622		125C, 5.25 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0624		125C, 5.5 VOLTS	192 HRS	72	0
HIGH TEMP OP LIFE	0624		125C, 5.25 VOLTS	1000 HRS	45	0
HIGH TEMP OP LIFE	0627		125C, 5.25 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0629		125C, 3.5 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0629		125C, 5.25 VOLTS	1000 HRS	76	0
HIGH TEMP OP LIFE	0629		125C, 5.25 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0642		125C, 5.5 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0705		125C, 3.6 VOLTS	192 HRS	77	0
HIGH TEMP OP LIFE	0711		125C, 5.5 VOLTS	192 HRS	45	0
HIGH TEMP OP LIFE	0713	* 1	125C, 5.5 VOLTS	192 HRS	77	0
Total:					0	0

W/E ENDURANCE AND DATA RET'N

DESCRIPTION	DATE CODE/SEQ	CONDITION	READPOINT	QTY	FAILS	FA#
WRITE CYCLE STRESS (CYS)	0538	50 C, 5.5 VOLTS	500 CYS	77	0	
STORAGE LIFE		150C	1000 HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0538	85 C, 5.5 VOLTS	5 KCYS	77	0	
		50 C, 5.5 VOLTS	25 KCYS	77	0	
STORAGE LIFE		150C	96 HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0538	85 C, 5.5 VOLTS	5 KCYS	77	0	
		50 C, 5.5 VOLTS	25 KCYS	77	0	
STORAGE LIFE		150C	96 HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0538	85 C, 5.5 VOLTS	5 KCYS	77	0	
		50 C, 5.5 VOLTS	25 KCYS	77	0	
STORAGE LIFE		150C	96 HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0538	50 C, 5.5 VOLTS	25 KCYS	77	0	
STORAGE LIFE		150C	96 HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0538	50 C, 5.5 VOLTS	25 KCYS	77	0	
STORAGE LIFE		150C	96 HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0538	50 C, 5.5 VOLTS	25 KCYS	77	0	
STORAGE LIFE		150C	96 HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0538	50 C, 5.5 VOLTS	25 KCYS	77	0	

STORAGE LIFE	0538	150C	96	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0538	50 C, 5.5 VOLTS	25	KCYS	77	0
STORAGE LIFE		150C	96	HRS	76	0
WRITE CYCLE STRESS (KCYS)	0538	50 C, 5.5 VOLTS	25	KCYS	77	0
STORAGE LIFE		150C	96	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0538	50 C, 5.5 VOLTS	25	KCYS	77	0
STORAGE LIFE		150C	96	HRS	76	0
WRITE CYCLE STRESS (KCYS)	0538	50 C, 5.5 VOLTS	25	KCYS	77	0
STORAGE LIFE		150C	96	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0541	85 C, 5.5 VOLTS	50	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0602	85 C, 5.5 V (PSA) & 15.0 V (PSB)	1	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0604	70 C, 5.5 VOLTS	30	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0604	85 C, 5.5 VOLTS	50	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0620	85 C, 5.25 VOLTS	50	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0622	85 C, 5.25 VOLTS	30	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0624	70 C, 5.5 VOLTS	50	KCYS	72	0
STORAGE LIFE		150C	1000	HRS	72	0
WRITE CYCLE STRESS (KCYS)	0627	85 C, 5.25 VOLTS	50	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0629	85 C, 3.5 VOLTS	10	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0629	25 C, 3.5 VOLTS	40	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0629	85 C, 5.25 VOLTS	50	KCYS	76	0
STORAGE LIFE		150C	1000	HRS	76	0
WRITE CYCLE STRESS (KCYS)	0629	85 C, 5.25 VOLTS	50	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0

WRITE CYCLE STRESS (KCYS)	0642	70 C, 5.5 VOLTS	30	KCYS	77	0
STORAGE LIFE		150C	1000	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0705	25 C, 3.6 VOLTS	200	KCYS	77	0
STORAGE LIFE		150C	96	HRS	77	0
WRITE CYCLE STRESS (KCYS)	0711	85 C, 5.25 VOLTS	30	KCYS	77	0
STORAGE LIFE		150C	500	HRS	77	0
STORAGE LIFE	0711	150C	96	HRS	77	0
WRITE CYCLE STRESS (KCYS)		85 C, 5.5 VOLTS	50	KCYS	77	0
WRITE CYCLE STRESS (KCYS)	0713	* 2 70 C, 5.5 VOLTS	30	KCYS	77	0
STORAGE LIFE		* 2 150C	96	HRS	77	0
			Total:			0

FAILURE RATE: MTTF (YRS): 110810 FITS: 1.0

DEVICE HOURS: 943032 FAILS: 0